Tuning the properties of boron-doped reduced graphene oxide by altering the boron content

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Supplementary data

SEM and EDS analysis

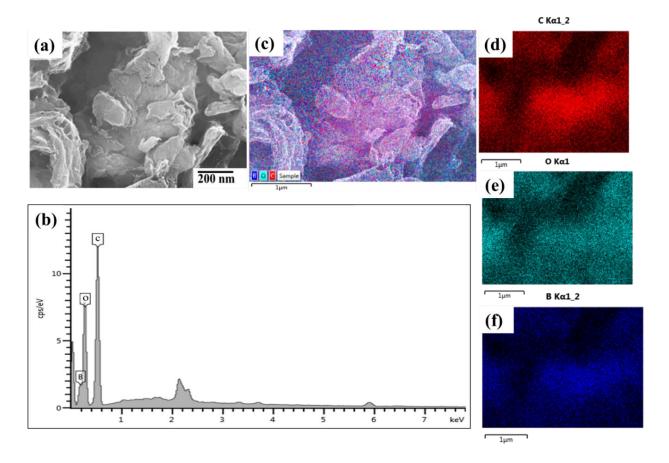


Figure S1: SEM and EDS measurements conducted in the selected area. (a) SEM image of B-rGO-70; and (b) EDS result, elemental mapping of (c) B-rGO, (d) carbon, (e) oxygen, and (f) boron

BET analysis

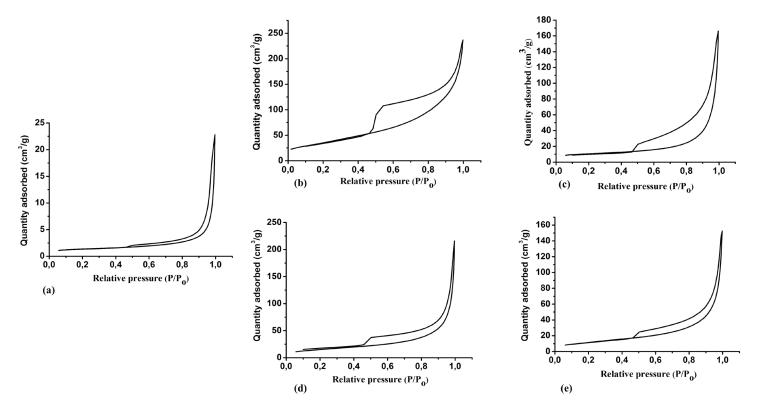


Figure S2: N₂ adsorption-desorption isotherms for (a) GO, (b) B-rGO-70, (c) B-rGO-60, (d) B-rGO-50 and (e) B-rGO-40

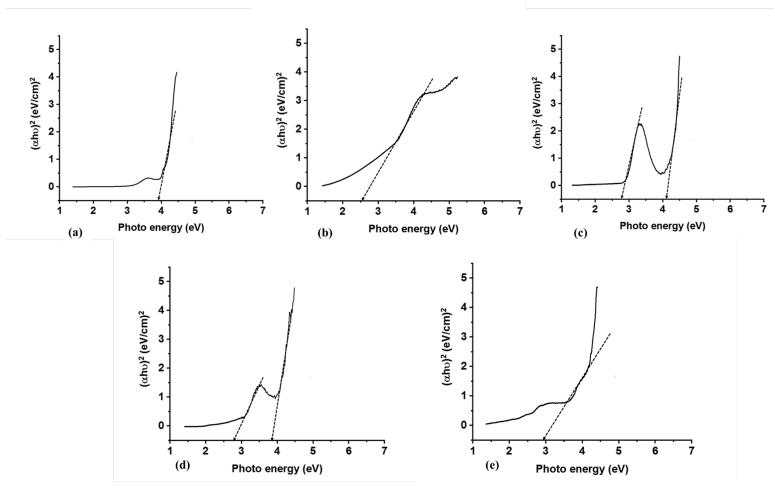


Figure S3: Figure S3: Tauc's plot for (a) GO, (b) B-rGO-70, (c) B-rGO-60, (d) B-rGO-50, and (e) B-rGO-40